Low-power 2-input NAND gate (open drain) Rev. 8 — 7 February 2022

Product data sheet

1. General description

The 74AUP1G38 is a single 2-input NAND gate with open-drain output. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

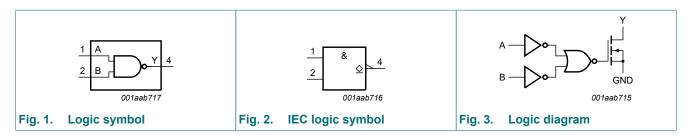
Type number	Package	Package						
	Temperature range	Name	Description	Version				
74AUP1G38GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G38GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP1G38GN	-40 °C to +125 °C	5 °C XSON6 extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm						
74AUP1G38GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74AUP1G38GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.35 mm	SOT1226				

4. Marking

Table 2. Marking	
Type number	Marking code[1]
74AUP1G38GW	aB
74AUP1G38GM	aB
74AUP1G38GN	aB
74AUP1G38GS	aB
74AUP1G38GX	aB

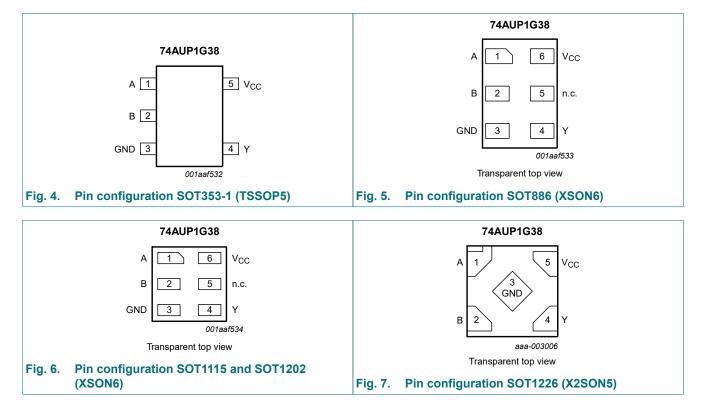
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin descriptionSymbol	Pin	Pin		
	TSSOP5 and X2SON5	XSON6		
A	1	1	data input	
В	2	2	data input	
GND	3	3	ground (0 V)	
Y	4	4	data output	
n.c.	-	5	not connected	
V _{CC}	5	6	supply voltage	

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF state.

Input		Output
Α	В	Y
L	L	Z
L	Н	Z
н	L	Z
Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V$ to V_{CC}		-	+20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: P_{tot} derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1226 (X2SON5) package: Ptot derates linearly with 3.0 mW/K above 67 °C.

9. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode and Power-down mode	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C	Image: space of the system of the				
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	$0.30 \times V_{CC}$	V
		V _{CC} = 0.9 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current		-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
Δl _{OFF}	additional power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
Δl _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	40	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.8	-	pF
Co	output capacitance	output enabled; V_0 = GND; V_{CC} = 0 V	-	1.7	-	pF
		output disabled; V_0 = GND; V_{CC} = 0 V	-	1.1	-	pF

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	40 °C to +85 °C	1				
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	$0.30 \times V_{CC}$	V
		V _{CC} = 0.9 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
l _{OZ}	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} (and at least one input LOW); $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	50	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C				-	
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.70 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	$0.25 \times V_{CC}$	V
		V _{CC} = 0.9 V to 1.95 V	-	-	$0.30 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.33 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} (and at least one input LOW); $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	$V_{1} \text{ or } V_{0} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	V_1 = GND or V_{CC} ; I_0 = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	75	μA
	1		1		1	1

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 9

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Typ[1]	Мах	Min	Max	Min	Max	
C _L = 5 p	F	· · · · · · · · · · · · · · · · · · ·								
t _{pd}		A or B to Y; see <u>Fig. 8</u> [2]								
	delay	V _{CC} = 0.8 V	-	13.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.9	4.6	10.4	1.8	11.4	1.8	12.6	ns
		V _{CC} = 1.4 V to 1.6 V	1.5	3.3	6.5	1.4	7.4	1.4	8.2	ns
		V _{CC} = 1.65 V to 1.95 V	1.2	2.9	5.1	1.1	5.9	1.1	6.5	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	2.2	3.8	0.9	4.5	0.9	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	0.9	2.3	4.0	0.8	4.5	0.8	4.9	ns
C _L = 10	pF								Ż	
t _{pd}	propagation	A or B to Y; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	16.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.3	5.6	12.3	2.1	13.7	2.1	15.1	ns
		V _{CC} = 1.4 V to 1.6 V	1.8	4.1	7.6	1.7	8.8	1.7	9.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.6	3.8	6.1	1.4	7.1	1.4	7.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	2.9	4.6	1.2	5.4	1.2	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	3.2	5.7	1.1	6.4	1.1	7.0	ns
C _L = 15	pF									
t _{pd}		A or B to Y; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	19.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.6	14.2	2.4	15.8	2.4	17.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.8	8.7	1.9	10.1	1.9	11.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	4.6	7.6	1.7	8.5	1.7	9.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	3.6	5.6	1.5	6.3	1.5	6.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	4.1	7.5	1.4	8.3	1.4	9.1	ns
C _L = 30	pF									
t _{pd}		A or B to Y; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	27.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	9.5	19.5	3.2	21.8	3.2	24.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.9	7.0	11.5	2.6	13.6	2.6	15.0	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	7.0	12.1	2.3	13.3	2.3	14.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	5.4	8.9	2.1	9.9	2.1	10.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.3	6.5	12.7	2.1	13.9	2.1	15.3	ns

Low-power 2-input NAND gate (open drain)

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF					•		-	
-10	dissipation	$f_i = 1 \text{ MHz};$ [3] V _I = GND to V _{CC}								
	capacitance	V _{CC} = 0.8 V	-	0.6	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	0.7	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	0.8	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	0.9	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	1.1	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	1.4	-	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PZL} and t_{PLZ} .

[3] \dot{C}_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N$ where:

f_i = input frequency in MHz;

V_{CC} = supply voltage in V;

N = number of inputs switching.

11.1. Waveforms and test circuit

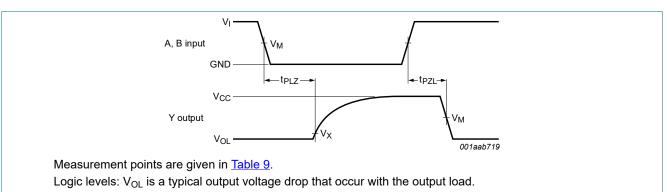


Fig. 8. The data input (A or B) to output (Y) propagation delays

Table 9. Measurement points

Supply voltage	Input			Output	Output		
V _{cc}	V _M	VI	t _r = t _f	V _M	V _X		
0.8 V to 1.6 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.1 V		
1.65 V to 2.7 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.15 V		
3.0 V to 3.6 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.3 V		

Low-power 2-input NAND gate (open drain)

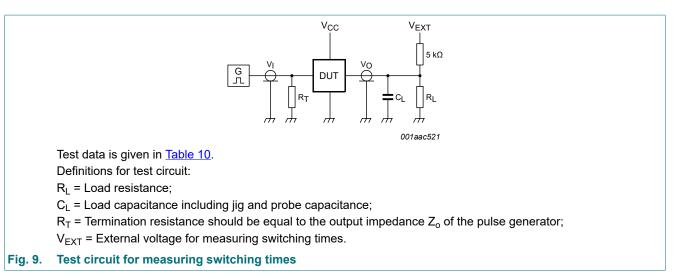


Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 $M\Omega.$

12. Package outline

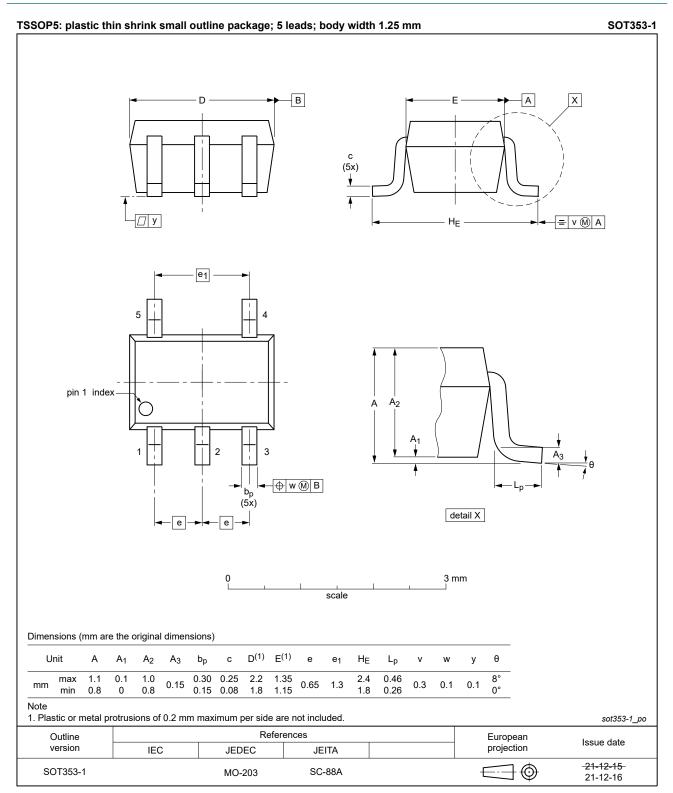


Fig. 10. Package outline SOT353-1 (TSSOP5)

Low-power 2-input NAND gate (open drain)

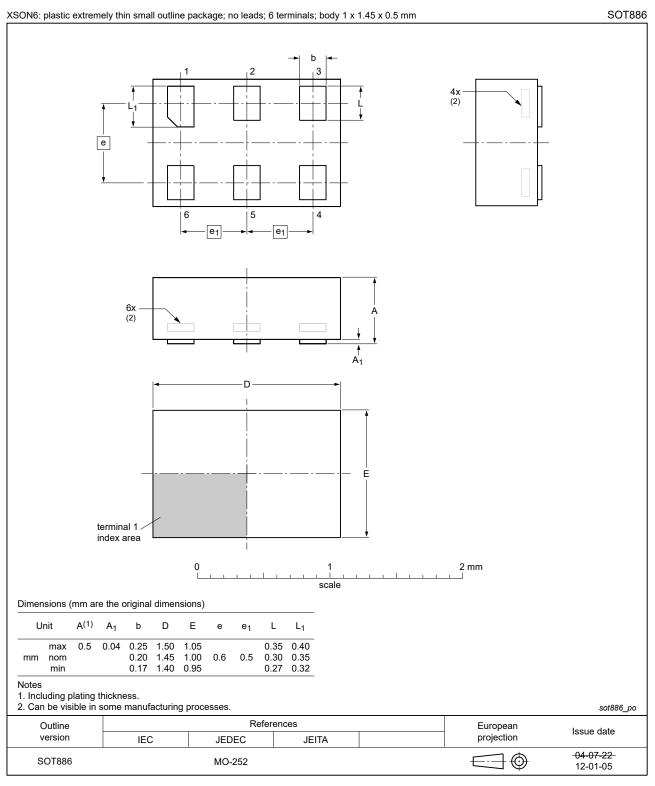
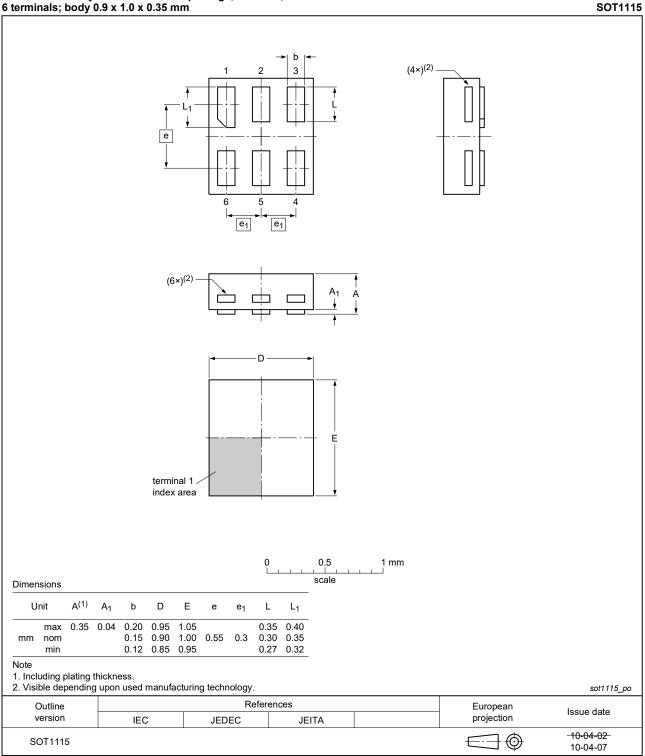


Fig. 11. Package outline SOT886 (XSON6)

Low-power 2-input NAND gate (open drain)

XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm





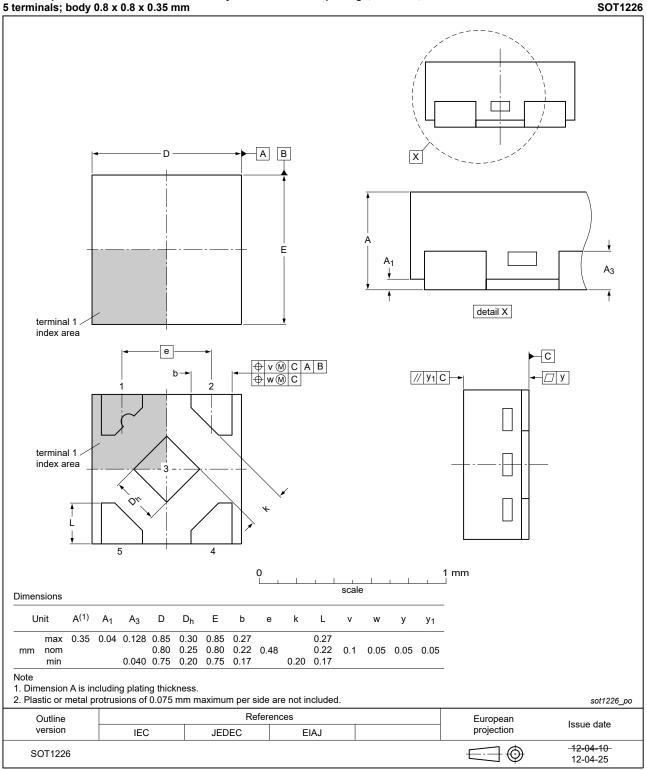
Low-power 2-input NAND gate (open drain)

terminals; body	1.0 x 1.0 x 0.35 mm		SOT12
	$(4\times)^{(2)}$		
	terminal 1 index area		
Dimensions	0 0.5 1 mm scale		
Unit A ⁽¹⁾	A ₁ b D E e e ₁ L L ₁		
mm nom min	0.04 0.20 1.05 1.05 0.35 0.40 0.15 1.00 1.00 0.55 0.35 0.30 0.35 0.12 0.95 0.95 0.27 0.32		
Note 1. Including plating 2. Visible dependin	hickness. g upon used manufacturing technology.		
Outline	References	European	sot1202_p
version	IEC JEDEC JEITA	projection	Issue date
SOT1202		$\neg \phi$	-10-04-02 -



Low-power 2-input NAND gate (open drain)

X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals: body 0.8 x 0.8 x 0.35 mm





13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G38 v.8	202220207	Product data sheet	-	74AUP1G38 v.7
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Fig. 10: Package outline drawing for SOT353-1 (TSSOP5) has changed. Type number 74AUP1G38GF (SOT891/XSON6) removed. Section 1 and Section 2 updated. Table 5: Derating values for P_{tot} total power dissipation updated. 			
74AUP1G38 v.7	20160404	Product data sheet	-	74AUP1G38 v.6
Modifications:	<u>Fig. 7</u> : Typo corrected in pin naming (pins A and B swapped)			
74AUP1G38 v.6	20120628 Product data sheet - 74AUP1G38		74AUP1G38 v.5	
Modifications:	 Added type number 74AUP1G38GX (SOT1226) Package outline drawing of SOT886 (Fig. 11) modified. 			
74AUP1G38 v.5	20111129	Product data sheet	-	74AUP1G38 v.4
Modifications:	Legal pages updated.			
74AUP1G38 v.4	20101007	Product data sheet	-	74AUP1G38 v.3
74AUP1G38 v.3	20090622	Product data sheet	-	74AUP1G38 v.2
74AUP1G38 v.2	20070614	Product data sheet	-	74AUP1G38 v.1
74AUP1G38 v.1	20061020	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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Low-power 2-input NAND gate (open drain)

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